

SGM4809 Dual 158mW Headphone Amplifier with Active Low Shutdown Mode

## **GENERAL DESCRIPTION**

The SGM4809 is a dual audio power amplifier capable of delivering 158mW per channel of continuous average power with less than 0.1% distortion (THD + N) when it drives a 16 $\Omega$  speaker from a 5.0V power supply. It is designed to maximize audio performance in portable applications such as mobile phone. The portable application requires audio power amplifier has minimum of external components and can operate from a single 2.5V to 5.5V power supply.

SGM4809 features an externally controlled, active-low, micropower consumption shutdown mode, as well as an internal thermal shutdown protection mechanism.

SGM4809 does not require bootstrap capacitors or snubber networks. It is optimally suited for low-power portable systems.

For maximum flexibility, the SGM4809 provides an externally controlled gain (with resistors), as well as an externally controlled turn-on time (with the bypass capacitor).

The SGM4809 is available in Pb-free MSOP-8 package. It operates over an ambient temperature range of -40°C to +85°C.

### **FEATURES**

- Active-Low Shutdown Mode
- 158mW into 16Ω Load from 5V Power Supply at THD+N = 0.1% Typical (per Channel)
- 87mW into 32Ω Load from 5V Power Supply at THD+N = 0.1% Typical (per Channel)
- Unity Gain Stable
- Shutdown Current: 0.6µA (TYP)
- 2.5V to 5.5V Operation
- Shutdown Pin is Compatible with 1.8V Logic
- Click and Pop Reduction Circuitry
- -40℃ to +85℃ Operating Temperature Range
- Pb-Free MSOP-8 Package

## **APPLICATIONS**

Portable Systems Headphone Amplifier Microphone Preamplifier Notebook Computers Mobile Phone PDAs GPS



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### **PACKAGE/ORDERING INFORMATION**

MODEL	ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION	MARKING INFORMATION		
SGM4809	SGM4809YMS/TR	MSOP-8	Tape and Reel, 3000	SGM4809YMS		

### PIN CONFIGURATION (Top View)



## ABSOLUTE MAXIMUM RATINGS

Supply Voltage	6V
Input Voltage	0.3V to (V <sub>+</sub> ) + 0.3V
Storage Temperature Range	65°C to +150°C
Junction Temperature	150°C
Operating Temperature Range	40°C to +85°C
Lead Temperature Range (Soldering 10 s	sec)
	260°C
ESD Susceptibility	
НВМ	4KV
ММ	400V

#### NOTES

1. Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.



## ELECTRICAL CHARACTERISTICS: $T_A = 25^{\circ}C$

DADAMETED	SYMBOL	CONDITIONS		SGM4809				
		CONDITIONS			MIN	TYP	MAX	UNITS
Supply Voltage	V+			2.5		5.5	V	
	I <sub>SD</sub>	V <sub>IN</sub> = 0V, V <sub>SHDN</sub> = GND, V <sub>+</sub> = 5.0V				0.6	4	μA
Shutdown Current		V <sub>IN</sub> = 0V, V <sub>SHDN</sub> = GND, V <sub>+</sub> = 3.3V			0.18			
		V <sub>IN</sub> = 0V, V <sub>SHDN</sub> = GND, V <sub>+</sub> = 2.6V			0.1			
	V <sub>os</sub>	$V_{IN} = 0V, V_{SHDN} = V_{+} = 5.0V$			-50	5.3	50	mV
Output Offset Voltage		$V_{IN} = 0V, V_{SHDN} = V_{+} = 3.3V$		-50	4.7	50		
		$V_{IN} = 0V, V_{SHDN} = V_{+} = 2.6V$		-50	4.4	50		
	Ι <sub>Q</sub>	$V_{IN} = 0V,$ $V_{SHDN} = V_{+}$	V <sub>+</sub> = 5.0V, No Load			1.83	2.8	mA
Quiescent Power Supply Current			V <sub>+</sub> = 3.3V, No Load			1.72		
			V <sub>+</sub> = 2.6V, No Load			1.65		
Shutdown Voltage Input High	V <sub>SDIH</sub>				1.8			V
Shutdown Voltage Input Low	V <sub>SDIL</sub>						0.4	V
	Po	f = 1kHz THD+N = 0.1%	V+ = 5.0V	R <sub>L</sub> = 16Ω		158		mW
				R <sub>L</sub> = 32Ω		87		
			V <sub>+</sub> = 3.6V	R <sub>L</sub> = 16Ω		84		
				R <sub>L</sub> = 32Ω		47		
Output Power (per Channer)			V+ = 3.0V	R <sub>L</sub> = 16Ω		58		
				R <sub>L</sub> = 32Ω		33		
			V <sub>+</sub> = 2.6V	R <sub>L</sub> = 16Ω		42		
				R <sub>L</sub> = 32Ω		25		
Total Harmonic Distortion + Noise	THD+N	$P_0$ = 78mW, V <sub>+</sub> = 5.0V, R <sub>L</sub> = 32Ω, f = 20Hz to 20kHz				0.3		%
Crosstalk	X <sub>talk</sub>	R <sub>L</sub> = 32Ω, P <sub>O</sub> = 70mW, V <sub>+</sub> = 5V, f = 1kHz				-100		dB
	PSRR			V <sub>+</sub> = 5.0V		-62		
		f - 017Uz		V+ = 3.6V		-62		
		1 = 217 HZ		V+ = 3.0V		-62		
Dower Supply Dejection Datio				V <sub>+</sub> = 2.6V		-62		dB
Power Supply Rejection Ratio				V <sub>+</sub> = 5.0V		-71		
				V+ = 3.6V		-71		
				V+ = 3.0V		-71		
				V <sub>+</sub> = 2.6V		-71		

Specifications subject to changes without notice.



## **TYPICAL APPLICATION**



# Dual 158mW Headphone Amplifier with Active Low Shutdown Mode

## **TYPICAL PERFORMANCE CHARACTERISTICS**





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## PACKAGE OUTLINE DIMENSIONS

#### **MSOP-8**



#### 04/2008 REV. A

SGMICRO is dedicated to provide high quality and high performance analog IC products to customers. All SGMICRO products meet the highest industry standards with strict and comprehensive test and quality control systems to achieve world-class consistency and reliability.

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